



#### **75V NPN MEDIUM POWER TRANSISTOR IN SOT89**

#### **Features**

- BV<sub>CEO</sub> > 75V
- I<sub>C</sub> = 3A high Continuous Current
- I<sub>CM</sub> = 10A Peak Pulse Current
- High Gain Holds up h<sub>FE</sub> > 300 @ I<sub>C</sub>=1A
- Low Equivalent On-Resistance; R<sub>CE(sat)</sub> = 78mΩ at 4.5A
- Excellent hFE characteristics up to 10A
- Totally Lead-Free & Fully RoHS compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

### **Applications**

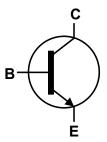
- Emergency Lighting Circuits
- Motor Driving (including DC fans)
- Solenoid, Relay and Actuator Drivers
- DC DC Modules
- Backlight Inverters
- Power Switches
- MOSFET Gate Drivers

# Mechanical Data

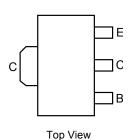
- Case: SOT89
- Case Material: Molded Plastic, "Green" Molding Compound UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 <a>®3</a>
- Weight: 0.052 grams (Approximate)







Device Symbol



Pin-Out

## **Ordering Information** (Note 4)

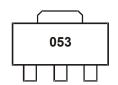
Part Number	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
FCX1053ATA	053	7	12	1,000
FCX1053A-13R	053	13	12	4,000

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

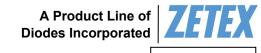
SOT89

### **Marking Information**



053 = Product Type Marking Code





FCX1053A

## Absolute Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V <sub>CBO</sub>	150	V
Collector-Emitter Voltage	V <sub>CEO</sub>	75	V
Emitter-Base Voltage	V <sub>EBO</sub>	7	V
Continuous Collector Current	Ic	3	Α
Base Current	I <sub>B</sub>	500	mA
Peak Pulse Current	I <sub>CM</sub>	10	Α

#### Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
	(Note 5)		1		
Power Dissipation	(Note 6)	$P_{D}$	1.6	W	
	(Note 7)		2.0		
	(Note 5)		125		
Thermal Resistance, Junction to Ambient Air	(Note 6)	$R_{ heta JA}$	78	°C/W	
	(Note 7)		62.5		
Thermal Resistance, Junction to Lead	(Note 8)	R <sub>0JL</sub>	3.6	°C/W	
Operating and Storage Temperature Range	$T_{J_i}T_{STG}$	-55 to +150	°C		

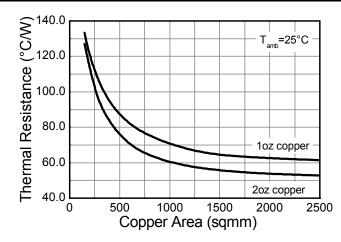
### ESD Ratings (Note 9)

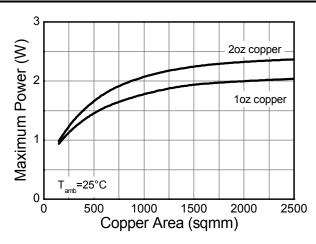
Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	٧	3A
Electrostatic Discharge - Machine Model	ESD MM	400	٧	С

Notes:

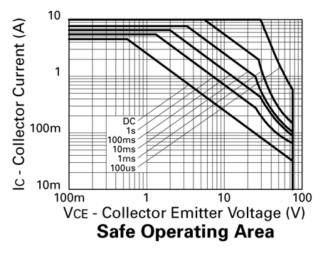
- 5. For a device mounted with the exposed collector pad on 15mm x 15mm 1oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.
- 6. Same as note (5), except the device is mounted on 25mm x 25mm 1oz copper.
- 7. Same as note (5), except the device is mounted on 50mm x 50mm 1oz copper.
- 8. Thermal resistance from junction to solder-point (on the exposed collector pad).
- 9. Refer to JEDEC specification JESD22-A114 and JESD22-A115.

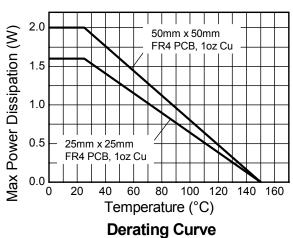
## **Thermal Characteristics and Derating Information**

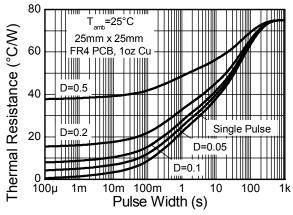


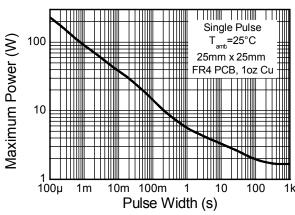






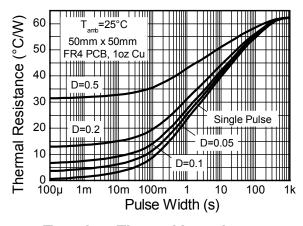


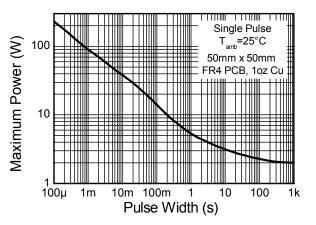




## **Transient Thermal Impedance**

**Pulse Power Dissipation** 





**Transient Thermal Impedance** 

**Pulse Power Dissipation** 





## **Electrical Characteristics** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

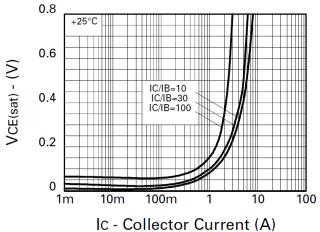
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV <sub>CBO</sub>	150	250	_	V	I <sub>C</sub> = 100μA
Collector-Emitter Breakdown Voltage	BV <sub>CES</sub>	150	250	_	V	I <sub>C</sub> = 100μA
Collector-Emitter Breakdown Voltage (Notes 10)	BV <sub>CEO</sub>	75	100	_	V	I <sub>C</sub> = 10mA
Collector-Emitter Breakdown Voltage	BV <sub>CEV</sub>	150	250	_	V	$I_C = 100\mu A, V_{EB} = 1V$
Emitter-Base Breakdown Voltage	BV <sub>EBO</sub>	7	8.8	_	V	I <sub>E</sub> = 100μA
Collector Cutoff Current	I <sub>CBO</sub>	_	0.9	50	nA	V <sub>CB</sub> = 120V
Collector Cutoff Current	I <sub>CES</sub>	_	1.5	50	nA	V <sub>CES</sub> = 120V
Emitter Cutoff Current	I <sub>EBO</sub>	_	0.3	20	nA	V <sub>EB</sub> = 5.6V
DC current transfer Static ratio (Notes 10)	h <sub>FE</sub>	270 300 300 40	440 450 450 60 20	1200		$I_{C}$ = 10mA, $V_{CE}$ = 2V $I_{C}$ = 0.5A, $V_{CE}$ = 2V $I_{C}$ = 1A, $V_{CE}$ = 2V $I_{C}$ = 4.5A, $V_{CE}$ = 2V $I_{C}$ = 10A, $V_{CE}$ = 2V
Collector-Emitter Saturation Voltage (Notes 10)	V <sub>CE(sat)</sub>	_	21 55 150 160 350	30 75 200 210 440	mV	$I_C = 0.2A, I_B = 20mA$ $I_C = 0.5A, I_B = 20mA$ $I_C = 1A, I_B = 10mA$ $I_C = 2A, I_B = 100mA$ $I_C = 4.5A, I_B = 200mA$
Base-Emitter Saturation Voltage (Notes 10)	$V_{BE(sat)}$		900	1000	mV	$I_C = 3A$ , $I_B = 100mA$
Base-Emitter Turn-on Voltage (Notes 10)	$V_{BE(on)}$		825	950	mV	$I_{C} = 3A, V_{CE} = 2V$
Transitional Frequency	f <sub>T</sub>	_	140	_	MHz	I <sub>C</sub> = 50mA, V <sub>CE</sub> = 10V, f = 100MHz
Output capacitance	C <sub>obo</sub>	_	21	30	pF	V <sub>CB</sub> = 10V, f = 1MHz,
Suitabing Time	t <sub>on</sub>		162		ns	V <sub>CC</sub> = 50V, I <sub>C</sub> = 2A,
Switching Time	t <sub>off</sub>	_	900	_	ns	$I_{B1} = I_{B2} = \pm 20 \text{mA}$

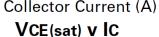
Note: 10. Measured under pulsed conditions. Pulse width =  $300\mu s$ . Duty cycle  $\leq 2\%$ .

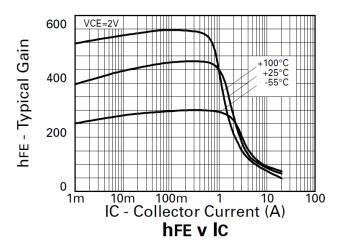


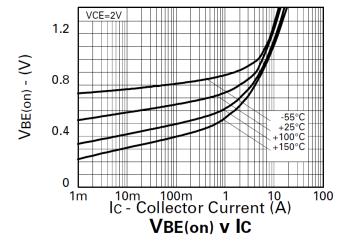


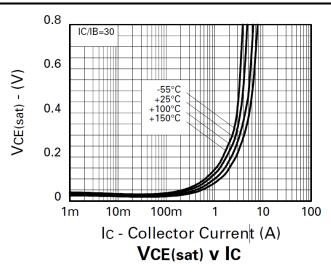
## Typical Electrical Characteristics (@TA = +25°C, unless otherwise specified.)

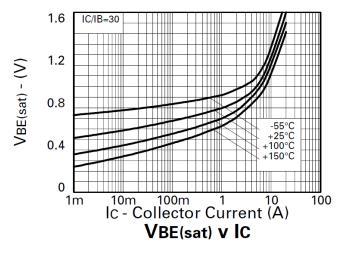








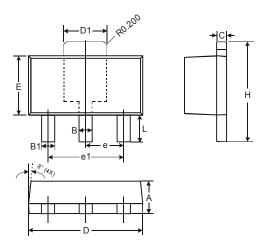






## **Package Outline Dimensions**

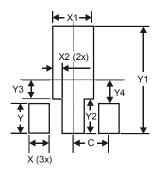
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



SOT89				
Dim	Min	Max		
Α	1.40	1.60		
В	0.44	0.62		
B1	0.35	0.54		
С	0.35	0.43		
D	4.40	4.60		
D1	1.52	1.83		
Е	2.29	2.60		
е	e 1.50 Typ			
e1	3.00 Typ			
Н	3.94	4.25		
L	0.89	1.20		
All Dimensions in mm				

## **Suggested Pad Layout**

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
Х	0.900
X1	1.733
X2	0.416
Υ	1.300
Y1	4.600
Y2	1.475
Y3	0.950
Y4	1.125
С	1.500





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